

TOSHIBA FIELD EFFECT TRANSISTOR SILICON N CHANNEL JUNCTION TYPE

2SK192A

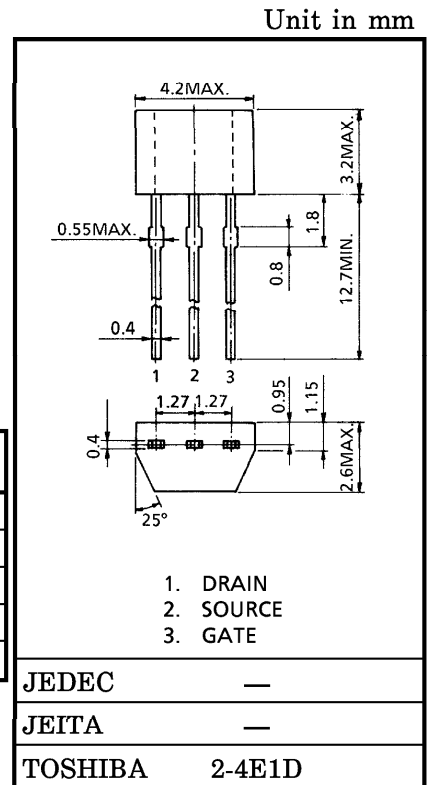
FM TUNER APPLICATIONS

VHF BAND AMPLIFIER APPLICATIONS

- High Power Gain : $G_{PS} = 24\text{dB (Typ.)}$ ($f = 100\text{ MHz}$)
- Low Noise Figure : $NF = 1.8\text{dB (Typ.)}$ ($f = 100\text{ MHz}$)
- High Forward Transfer Admittance
: $|y_{fs}| = 7\text{ mS (Typ.)}$ ($f = 1\text{ kHz}$)

MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Gate-Drain Voltage	V_{GDO}	-18	V
Gate Current	I_G	10	mA
Drain Power Dissipation	P_D	200	mW
Junction Temperature	T_j	125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55~125	$^\circ\text{C}$

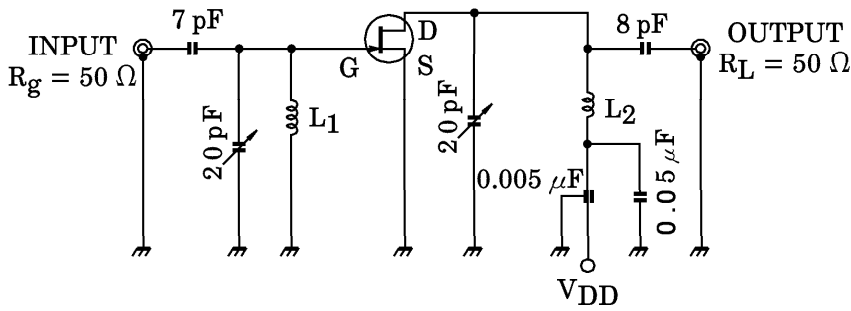


Weight : 0.13 g

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage Current	I_{GSS}	$V_{GS} = -1.0\text{ V}, V_{DS} = 0$	—	—	-10	nA
Gate-Drain Breakdown Voltage	$V_{(BR)GDO}$	$I_G = -100\ \mu\text{A}$	-18	—	—	V
Drain Current	I_{DSS} (Note)	$V_{GS} = 0, V_{DS} = 10\text{ V}$	3	—	24	mA
Gate-Source Cut-off Voltage	$V_{GS(OFF)}$	$V_{DS} = 10\text{ V}, I_D = 1\ \mu\text{A}$	-1.2	-3	—	V
Forward Transfer Admittance	$ y_{fs} $	$V_{GS} = 0, V_{DS} = 10\text{ V}, f = 1\text{ kHz}$	—	7	—	mS
Input Capacitance	C_{iss}	$V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	3.5	—	pF
Reverse Transfer Capacitance	C_{rss}	$V_{GD} = -10\text{ V}, f = 1\text{ MHz}$	—	—	0.65	pF
Power Gain	G_{PS}	$V_{DD} = 10\text{ V}, f = 100\text{ MHz}$ (Fig.1)	—	24	—	dB
Noise Figure	NF	$V_{DD} = 10\text{ V}, f = 100\text{ MHz}$ (Fig.1)	—	1.8	3.5	dB

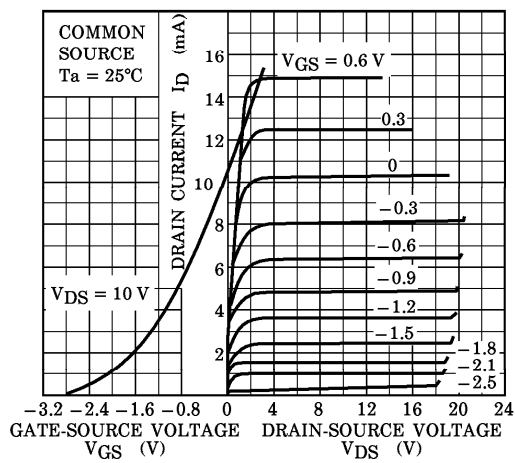
(Note) : I_{DSS} Classification Y : 3.0~7.0, GR : 6.0~14.0, BL : 12.0~24.0



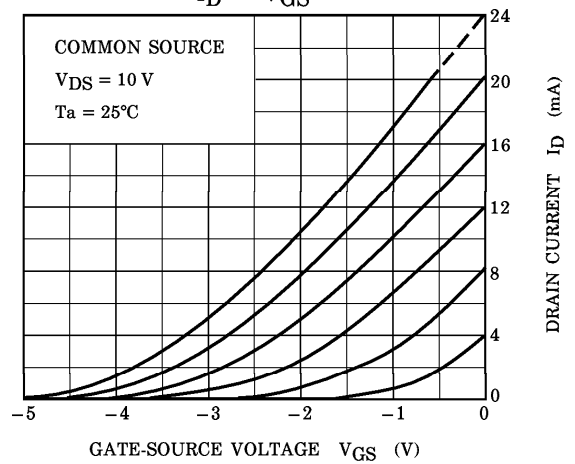
L₁ : 0.8 mm φ Ag PLATED Cu WIRE 3 TURNS, 10 mm I_D, 10 mm LENGTH
 L₂ : 0.8 mm φ Ag PLATED Cu WIRE 3.5 TURNS, 10 mm I_D, 10 mm LENGTH

Fig.1 100 MHz G_{ps}, NF TEST CIRCUIT

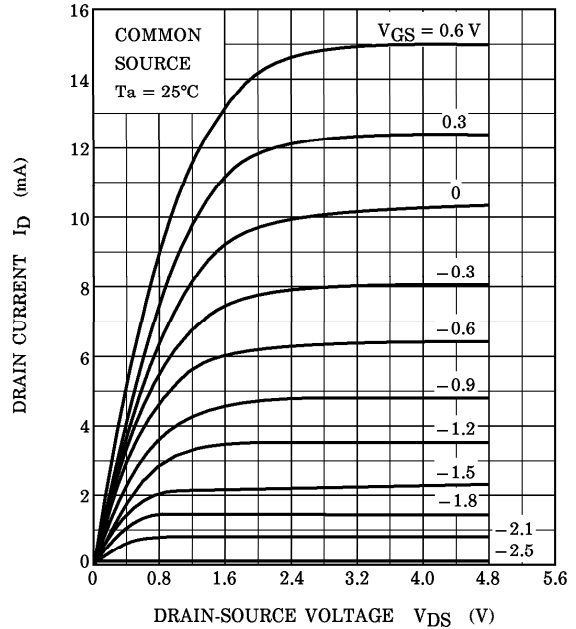
STATIC CHARACTERISTICS



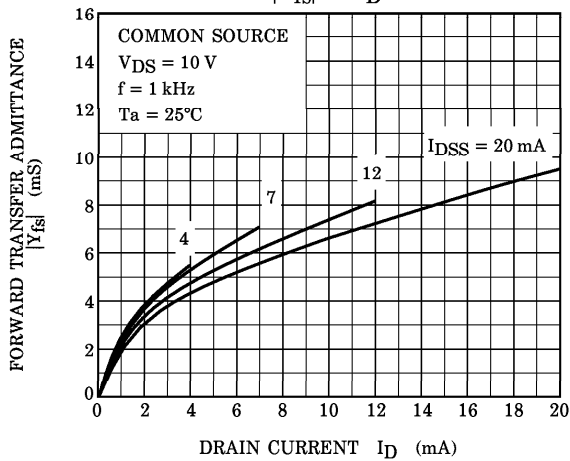
I_D - V_{GS}

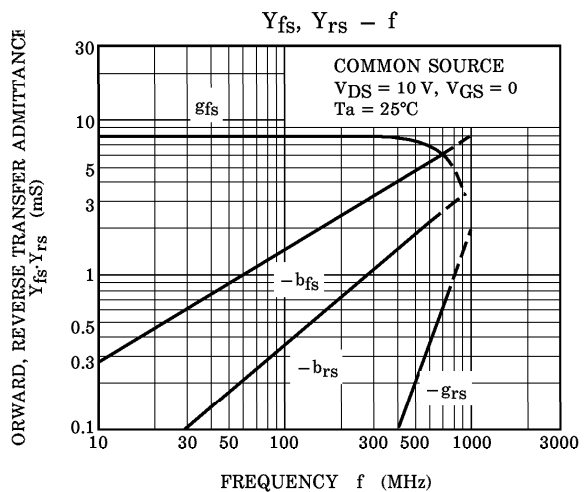
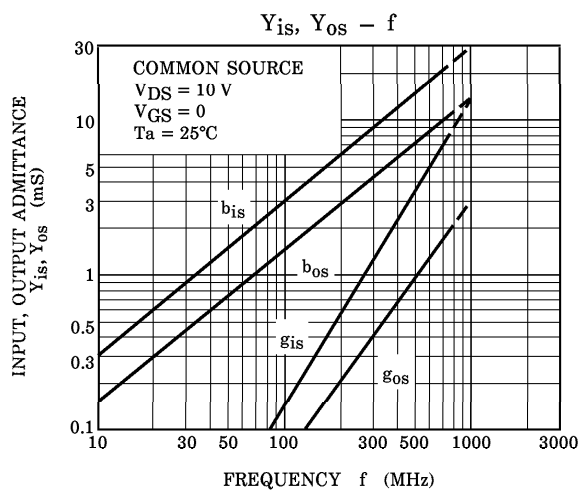
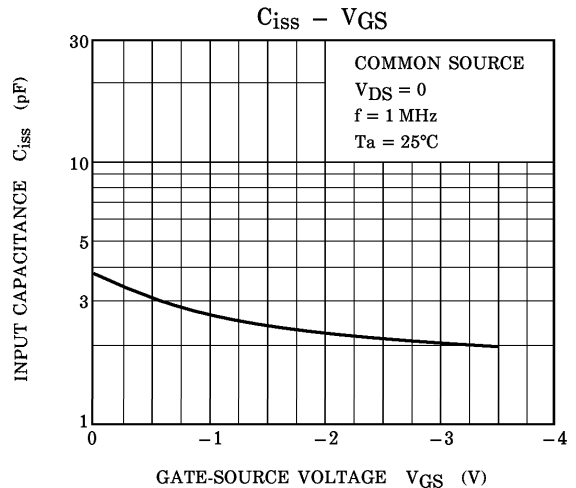
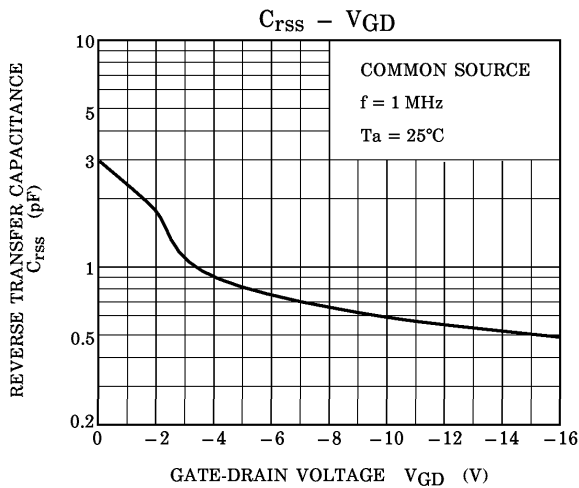
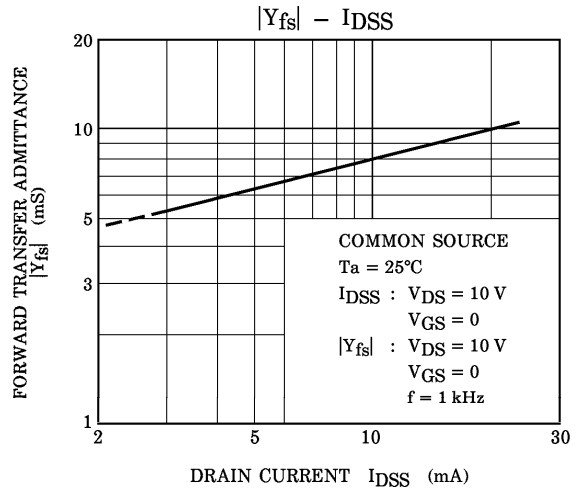
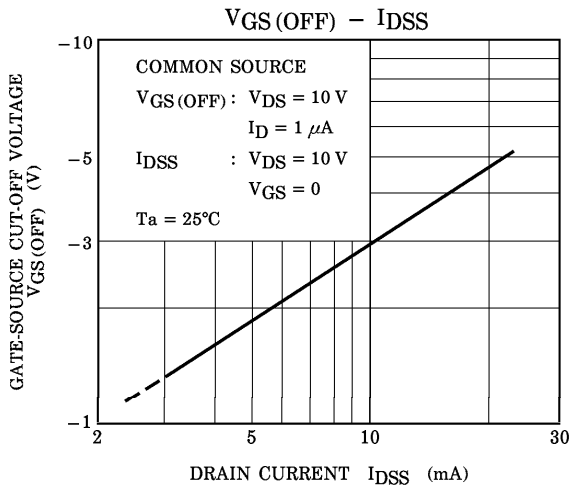


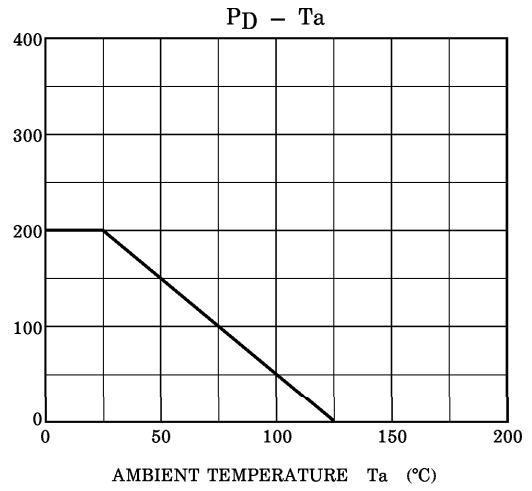
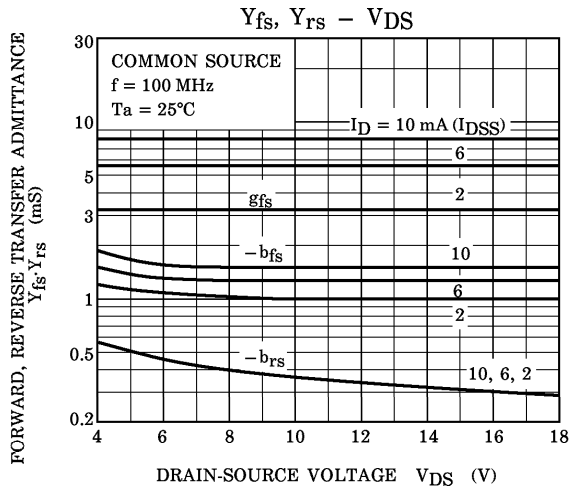
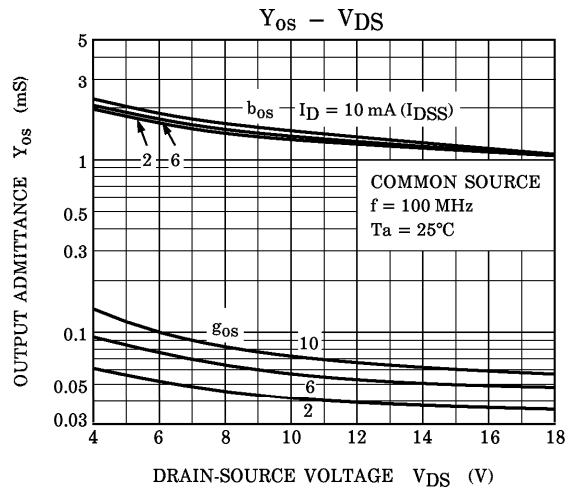
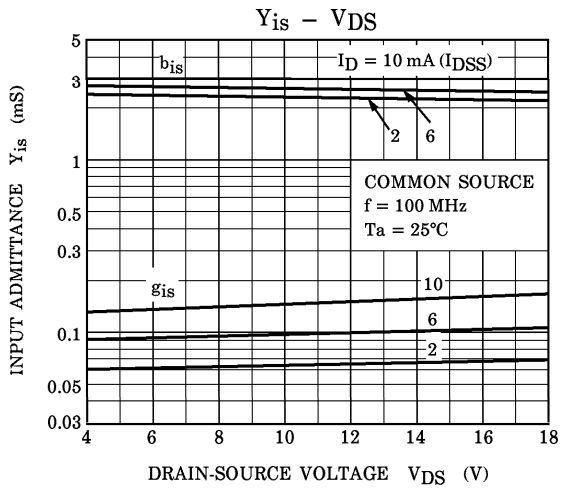
I_D - V_{DS} (LOW VOLTAGE REGION)



|Y_{fs}| - I_D







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